

芯伯乐®
X I N B O L E

Product Specification

XBLW SN74LS85

4-bit Magnitude Comparator

WEB | www.xinboleic.com



Description

The SN74LS85 is a 4-bit magnitude comparator that can be expanded to almost any length. They perform comparison of two 4-bit binary, BCD or other monotonic codes and present the three possible magnitude results at the outputs ($QA > B$, $QA = B$ and $QA < B$). The 4-bit inputs are weighted (A_0 to A_3 and B_0 to B_3), where A_3 and B_3 are the most significant bits. For proper compare operation the expander inputs ($IA > B$, $IA = B$ and $IA < B$) to the least significant position must be connected as follows: $IA < B = IA > B = \text{LOW}$ and $IA = B = \text{HIGH}$. For words greater than 4-bits, units can be cascaded by connecting outputs $QA > B$, $QA = B$ and $QA < B$ to the corresponding inputs of the significant comparator. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Features

- Wide supply voltage range from 2.0 to 6.0V
- CMOS low power dissipation
- CMOS Input levels
- Specified from -20°C to +85°C
- Packaging information: DIP16/SOP16/TSSOP16

Applications

- Process controllers
- Servo-motor control



Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
XBLW SN74LS85N	DIP-16	74LS85N	Tube	1000Pcs/Box
XBLW SN74LS85DTR	SOP-16	74LS85	Tape	2500Pcs/Reel
XBLW SN74LS85TDTR	TSSOP-16	74LS85	Tape	3000Pcs/Reel

Block Diagram

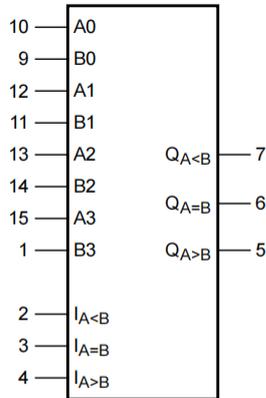


Figure 1. Logic symbol

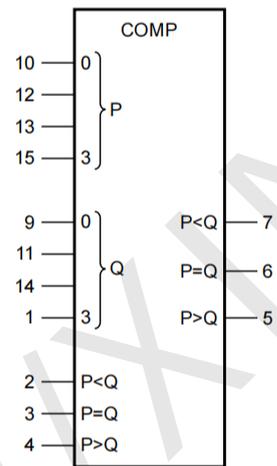


Figure 2. IEC logic symbol

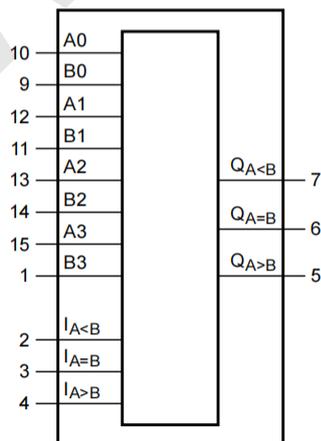


Figure 3. Functional diagram

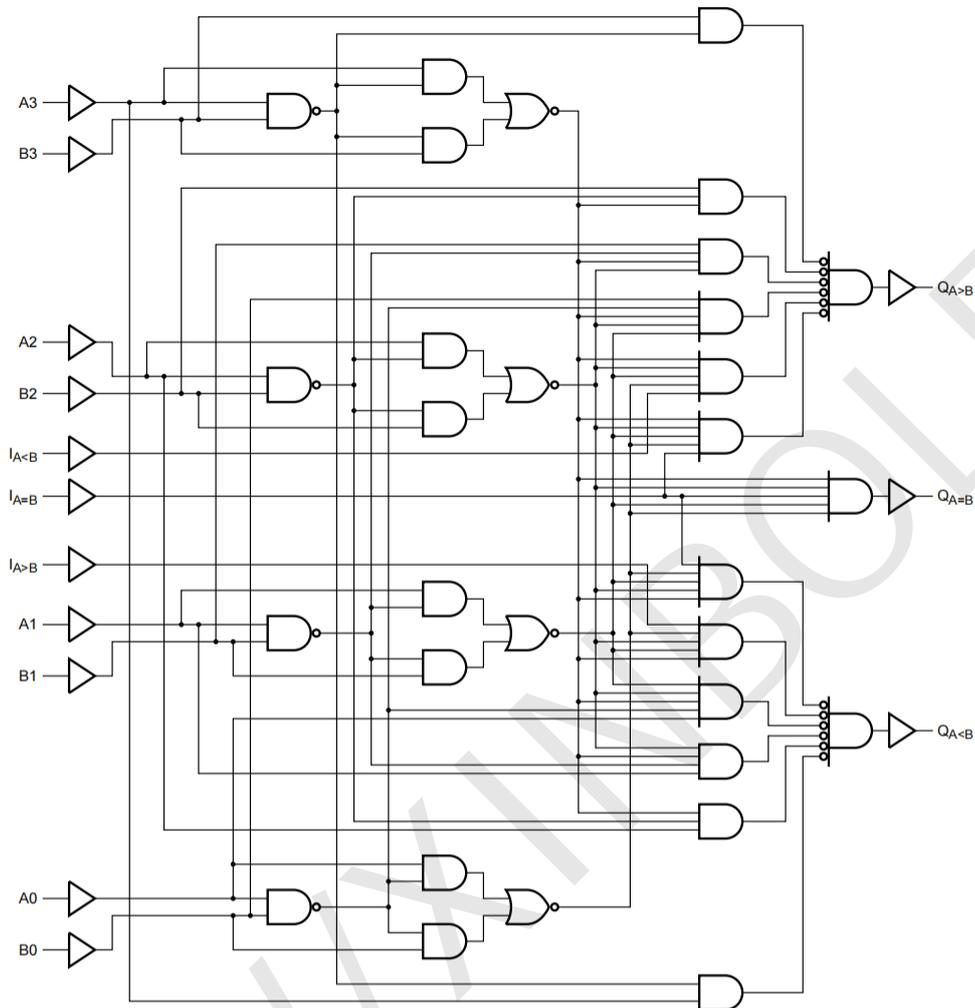
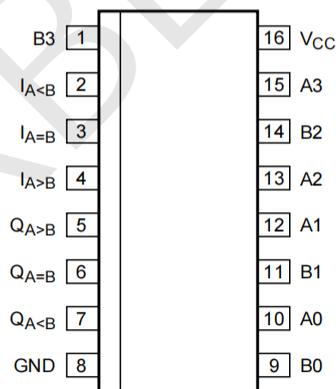
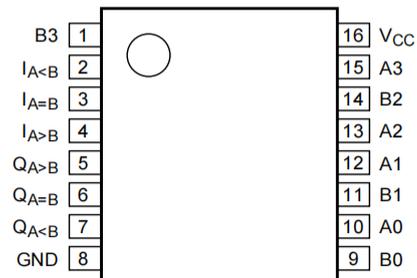


Figure 4. Logic diagram

Pin Configurations



DIP 16 SOP-16



TSSOP-16

Pin Description

Pin No.	Pin Name	Description
1	B3	word B input
2	I _{A<B}	A<B expansion input
3	I _{A=B}	A=B expansion input
4	I _{A>B}	A>B expansion input
5	Q _{A>B}	A>B output
6	Q _{A=B}	A=B output
7	Q _{A<B}	A<B output
8	GND	ground (0V)
9	B0	word B input
10	A0	word A input
11	B1	word B input
12	A1	word A input
13	A2	word A input
14	B2	word B input
15	A3	word A input
16	V _{CC}	supply voltage

Function Table

Comparing input				Cascading input			Output		
A3, B3	A2, B2	A1, B1	A0, B0	I _{A>B}	I _{A<B}	I _{A=B}	Q _{A>B}	Q _{A<B}	Q _{A=B}
A3>B3	X	X	X	X	X	X	H	L	L
A3<B3	X	X	X	X	X	X	L	H	L
A3=B3	A2>B2	X	X	X	X	X	H	L	L
A3=B3	A2<B2	X	X	X	X	X	L	H	L
A3=B3	A2=B2	A1>B1	X	X	X	X	H	L	L
A3=B3	A2=B2	A1<B1	X	X	X	X	L	H	L
A3=B3	A2=B2	A1=B1	A0>B0	X	X	X	H	L	L
A3=B3	A2=B2	A1=B1	A0<B0	X	X	X	L	H	L
A3=B3	A2=B2	A1=B1	A0=B0	H	L	L	H	L	L
A3=B3	A2=B2	A1=B1	A0=B0	L	H	L	L	H	L
A3=B3	A2=B2	A1=B1	A0=B0	L	L	H	L	L	H
A3=B3	A2=B2	A1=B1	A0=B0	X	X	H	L	L	H
A3=B3	A2=B2	A1=B1	A0=B0	H	H	L	L	L	L
A3=B3	A2=B2	A1=B1	A0=B0	L	L	L	H	H	L

Note: H=HIGH voltage level; L=LOW voltage level; X=don't care.

Electrical Parameter

Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+7.0	V
input clamping current	I_{IK}	$V_I < -0.5V$ or $V_I > V_{CC}+0.5V$	-	± 20	mA
output clamping current	I_{OK}	$V_O < -0.5V$ or $V_O > V_{CC}+0.5V$	-	± 20	mA
output current	I_O	$-0.5V < V_O < V_{CC}+0.5V$	-	± 25	mA
supply current	I_{CC}	-	-	50	mA
ground current	I_{GND}	-	-50	-	mA
storage temperature	T_{stg}	-	-65	+150	°C
total power dissipation	P_{tot}	-	-	500	mW
soldering temperature	T_L	10s	DIP	245	°C
			SOP	250	

Note:

- [1] For DIP16 packages: above 70°C the value of P_{tot} derates linearly with 12mW/K.
- [2] For SOP16 packages: above 70°C the value of P_{tot} derates linearly with 8mW/K.
- [3] For (T)SSOP16 packages: above 60°C the value of P_{tot} derates linearly with 5.5mW/K.

Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	2.0	5.0	6.0	V
input voltage	V_I	-	0	-	V_{CC}	V
output voltage	V_O	-	0	-	V_{CC}	V
input transition rise and fall rate	$\Delta t/\Delta V$	$V_{CC}=2.0V$	-	-	625	ns/V
		$V_{CC}=4.5V$	-	1.67	139	ns/V
		$V_{CC}=6.0V$	-	-	83	ns/V
ambient temperature	T_{amb}	-	-20	-	+85	°C

Electrical Characteristics

DC Characteristics 1

($T_{amb}=25^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0\text{V}$	1.5	1.2	-	V	
		$V_{CC}=4.5\text{V}$	3.15	2.4	-	V	
		$V_{CC}=6.0\text{V}$	4.2	3.2	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=2.0\text{V}$	-	0.8	0.5	V	
		$V_{CC}=4.5\text{V}$	-	2.1	1.35	V	
		$V_{CC}=6.0\text{V}$	-	2.8	1.8	V	
HIGH-level output voltage	V_{OH}	$V_I=V_{IH}$ or V_{IL}	$I_o=-20\mu\text{A}; V_{CC}=2.0\text{V}$	1.9	2.0	-	V
			$I_o=-20\mu\text{A}; V_{CC}=4.5\text{V}$	4.4	4.5	-	V
			$I_o=-20\mu\text{A}; V_{CC}=6.0\text{V}$	5.9	6.0	-	V
			$I_o=-4.0\text{mA}; V_{CC}=4.5\text{V}$	3.98	4.32	-	V
			$I_o=-5.2\text{mA}; V_{CC}=6.0\text{V}$	5.48	5.81	-	V
LOW-level output voltage	V_{OL}	$V_I=V_{IH}$ or V_{IL}	$I_o=20\mu\text{A}; V_{CC}=2.0\text{V}$	-	0	0.1	V
			$I_o=20\mu\text{A}; V_{CC}=4.5\text{V}$	-	0	0.1	V
			$I_o=20\mu\text{A}; V_{CC}=6.0\text{V}$	-	0	0.1	V
			$I_o=4.0\text{mA}; V_{CC}=4.5\text{V}$	-	0.15	0.26	V
			$I_o=5.2\text{mA}; V_{CC}=6.0\text{V}$	-	0.16	0.26	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=6.0\text{V}$	-	-	± 0.1	μA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_o=0\text{A}; V_{CC}=6.0\text{V}$	-	-	8.0	μA	
input capacitance	C_I	-	-	3.5	-	pF	

DC Characteristics 2

($T_{amb}=-20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0\text{V}$	1.5	-	-	V	
		$V_{CC}=4.5\text{V}$	3.15	-	-	V	
		$V_{CC}=6.0\text{V}$	4.2	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=2.0\text{V}$	-	-	0.5	V	
		$V_{CC}=4.5\text{V}$	-	-	1.35	V	
		$V_{CC}=6.0\text{V}$	-	-	1.8	V	
HIGH-level output voltage	V_{OH}	$V_I=V_{IH}$ or V_{IL}	$I_o=-20\mu\text{A}; V_{CC}=2.0\text{V}$	1.9	-	-	V
			$I_o=-20\mu\text{A}; V_{CC}=4.5\text{V}$	4.4	-	-	V
			$I_o=-20\mu\text{A}; V_{CC}=6.0\text{V}$	5.9	-	-	V
			$I_o=-4.0\text{mA}; V_{CC}=4.5\text{V}$	3.84	-	-	V
			$I_o=-5.2\text{mA}; V_{CC}=6.0\text{V}$	5.34	-	-	V
LOW-level output voltage	V_{OL}	$V_I=V_{IH}$ or V_{IL}	$I_o=20\mu\text{A}; V_{CC}=2.0\text{V}$	-	-	0.1	V
			$I_o=20\mu\text{A}; V_{CC}=4.5\text{V}$	-	-	0.1	V
			$I_o=20\mu\text{A}; V_{CC}=6.0\text{V}$	-	-	0.1	V
			$I_o=4.0\text{mA}; V_{CC}=4.5\text{V}$	-	-	0.33	V
			$I_o=5.2\text{mA}; V_{CC}=6.0\text{V}$	-	-	0.33	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=6.0\text{V}$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_o=0\text{A}; V_{CC}=6.0\text{V}$	-	-	80	μA	

AC Characteristics 1

($T_{amb}=25^{\circ}\text{C}$, $\text{GND}=0\text{V}$, $C_L=50\text{pF}$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
propagation delay	t_{pd}	An, Bn to $Q_{A>B}$; An, Bn to $Q_{A<B}$; see Figure 6[1]	$V_{CC}=2.0\text{V}$	-	63	195	ns
			$V_{CC}=4.5\text{V}$	-	23	39	ns
			$V_{CC}=5.0\text{V}; C_L=15\text{pF}$	-	20	-	ns
			$V_{CC}=6.0\text{V}$	-	18	33	ns
		An, Bn to $Q_{A=B}$; see Figure 6	$V_{CC}=2.0\text{V}$	-	58	175	ns
			$V_{CC}=4.5\text{V}$	-	21	35	ns
			$V_{CC}=5.0\text{V}; C_L=15\text{pF}$	-	18	-	ns
			$V_{CC}=6.0\text{V}$	-	17	30	ns
		$I_{A=B}$ or $I_{A>B}$ to $Q_{A<B}$; $I_{A<B}$ or $I_{A=B}$ to $Q_{A>B}$; see Figure 6	$V_{CC}=2.0\text{V}$	-	50	140	ns
			$V_{CC}=4.5\text{V}$	-	18	28	ns
			$V_{CC}=5.0\text{V}; C_L=15\text{pF}$	-	15	-	ns
			$V_{CC}=6.0\text{V}$	-	14	24	ns
		$I_{A=B}$ to $Q_{A=B}$; see Figure 6	$V_{CC}=2.0\text{V}$	-	39	120	ns
			$V_{CC}=4.5\text{V}$	-	14	24	ns
			$V_{CC}=5.0\text{V}; C_L=15\text{pF}$	-	11	-	ns
			$V_{CC}=6.0\text{V}$	-	11	20	ns
transition time	t_t	see Figure 6[2]	$V_{CC}=2.0\text{V}$	-	19	75	ns
			$V_{CC}=4.5\text{V}$	-	7	15	ns
			$V_{CC}=6.0\text{V}$	-	6	13	ns
power dissipation capacitance	C_{PD}	per package; $V_I=\text{GND}$ to $V_{CC[3]}$	-	18	-	pF	

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D=C_{PD}\times V_{CC}^2\times f_i+\Sigma(C_L\times V_{CC}^2\times f_o)$ where:

f_i =input frequency in MHz; f_o =output frequency in MHz;

C_L =output load capacitance in pF;

V_{CC} =supply voltage in V;

$\Sigma(C_L\times V_{CC}^2\times f_o)$ =sum of outputs.

AC Characteristics 2

($T_{amb} = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $GND = 0\text{V}$, $C_L = 50\text{pF}$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
propagation delay	t_{pd}	An, Bn to $Q_{A>B}$; An, Bn to $Q_{A<B}$; see Figure 6[1]	$V_{CC} = 2.0\text{V}$	-	-	245	ns
			$V_{CC} = 4.5\text{V}$	-	-	49	ns
			$V_{CC} = 6.0\text{V}$	-	-	42	ns
		An, Bn to $Q_{A=B}$; see Figure 6	$V_{CC} = 2.0\text{V}$	-	-	220	ns
			$V_{CC} = 4.5\text{V}$	-	-	44	ns
			$V_{CC} = 6.0\text{V}$	-	-	37	ns
		$I_{A=B}$ or $I_{A>B}$ to $Q_{A<B}$; $I_{A<B}$ or $I_{A=B}$ to $Q_{A>B}$; see Figure 6	$V_{CC} = 2.0\text{V}$	-	-	175	ns
			$V_{CC} = 4.5\text{V}$	-	-	35	ns
			$V_{CC} = 6.0\text{V}$	-	-	30	ns
		$I_{A=B}$ to $Q_{A=B}$; see Figure 6	$V_{CC} = 2.0\text{V}$	-	-	150	ns
			$V_{CC} = 4.5\text{V}$	-	-	30	ns
			$V_{CC} = 6.0\text{V}$	-	-	26	ns
transition time	t_t	see Figure 6[2]	$V_{CC} = 2.0\text{V}$	-	-	95	ns
			$V_{CC} = 4.5\text{V}$	-	-	19	ns
			$V_{CC} = 6.0\text{V}$	-	-	16	ns

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_t is the same as t_{THL} and t_{TLH} .

Testing Circuit

AC Testing Circuit

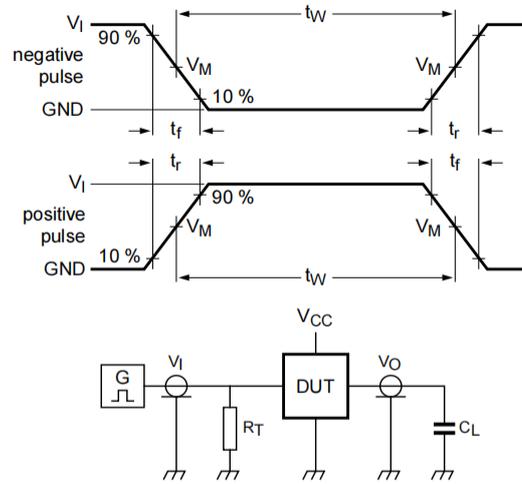


Figure 5. Test circuit for measuring switching times

Definitions for test circuit:

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance should be equal to the output impedance Z_o of the pulse generator.

AC Testing Waveforms

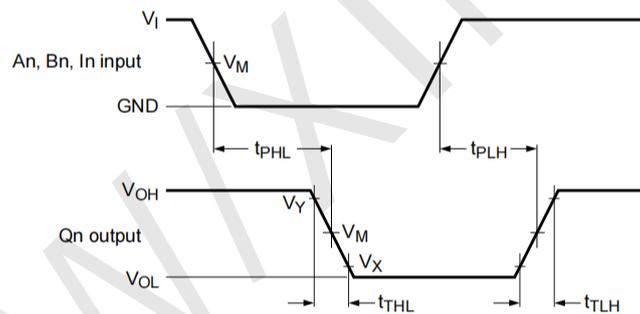


Figure 6. Word A inputs (A_n), word B inputs (B_n) and expansion inputs (I_n) to the outputs (Q_n) propagation delays and the output transition times

Measurement Points

Type	Input		Output		
	V_I	V_M	V_M	V_X	V_Y
SN74LS85	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$

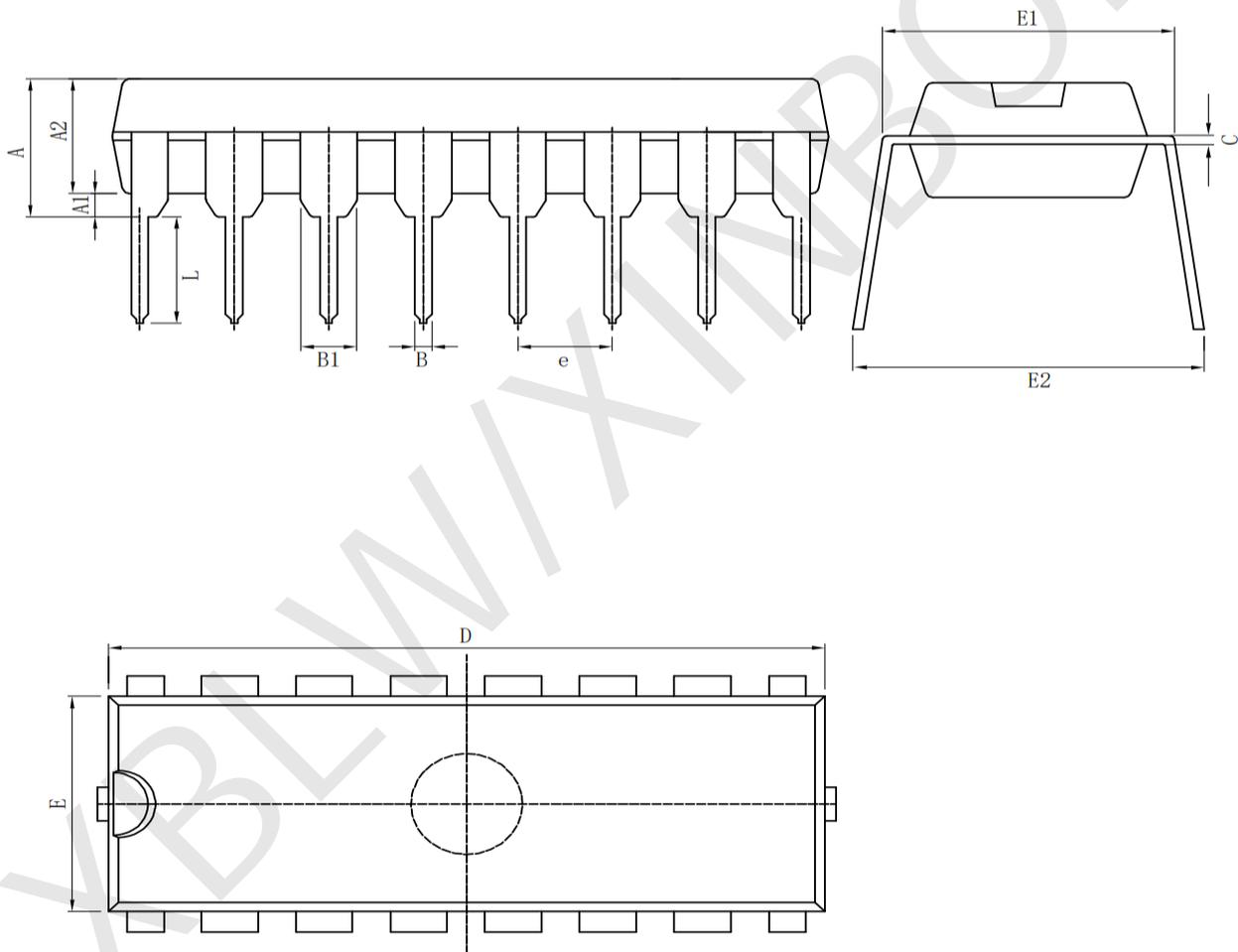
Test Data

Type	Input		Load	Test
	V_I	t_r, t_f	C_L	
SN74LS85	V_{CC}	6ns	15pF, 50pF	t_{PHL}, t_{PLH}

Package Information

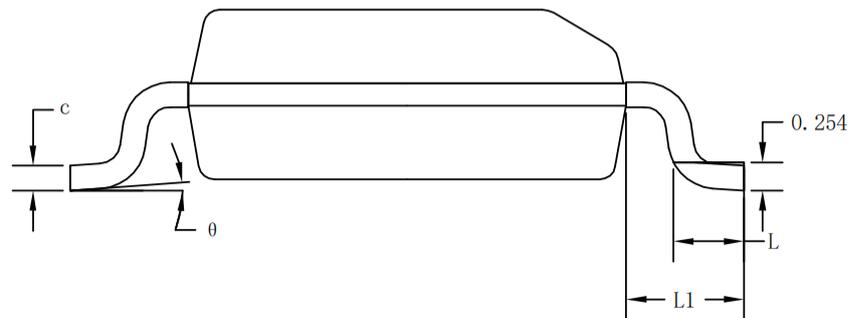
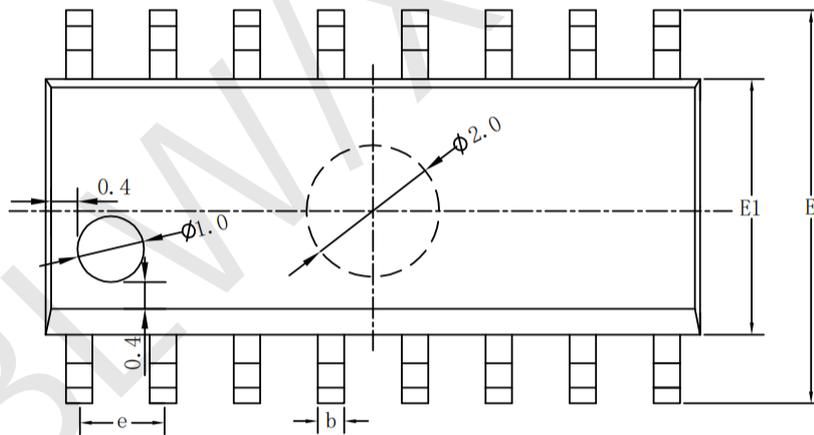
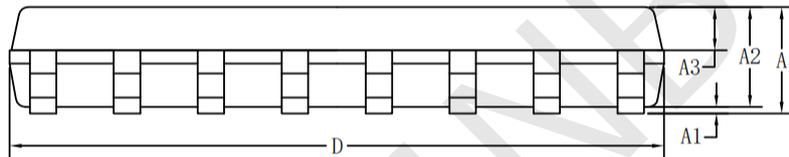
· DIP-16

Symbol	Size		Dimensions In Millimeters		Symbol	Size		Dimensions In Inches	
	Min (mm)	Max (mm)	Min (in)	Max (in)		Min (in)	Max (in)		
A	3.710	4.310	A	0.146	0.170				
A1	0.510		A1	0.020					
A2	3.200	3.600	A2	0.126	0.142				
B	0.380	0.570	B	0.015	0.022				
B1	1.524 (BSC)		B1	0.060 (BSC)					
C	0.204	0.360	C	0.008	0.014				
D	18.80	19.20	D	0.740	0.756				
E	6.200	6.600	E	0.244	0.260				
E1	7.320	7.920	E1	0.288	0.312				
e	2.540 (BSC)		e	0.100 (BSC)					
L	3.000	3.600	L	0.118	0.142				
E2	8.400	9.000	E2	0.331	0.354				



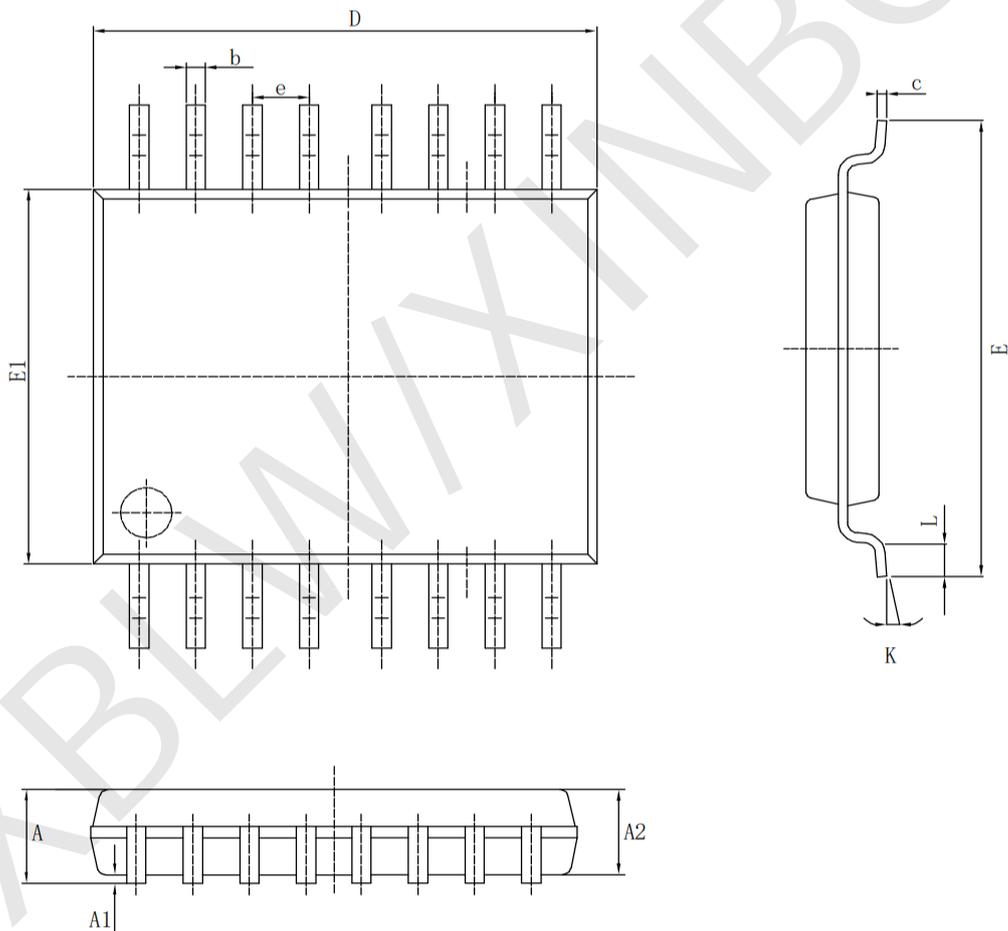
· SOP-16

Symbol	Size	Dimensions In Millimeters			Symbol	Size	Dimensions In Inches		
		Min (mm)	Nom (mm)	Max (mm)			Min (in)	Nom (in)	Max (in)
A		1.500	1.600	1.700	A		0.059	0.063	0.067
A1		0.100	0.150	0.250	A1		0.004	0.006	0.010
A2		1.400	1.450	1.500	A2		0.055	0.057	0.059
A3		0.600	0.650	0.700	A3		0.024	0.026	0.028
b		0.300	0.400	0.500	b		0.012	0.016	0.020
c		0.150	0.200	0.250	c		0.006	0.008	0.010
D		9.800	9.900	10.00	D		0.386	0.390	0.394
E		5.800	6.000	6.200	E		0.228	0.236	0.244
E1		3.850	3.900	3.950	E1		0.152	0.154	0.156
e		1.27 (BSC)			e		0.050 (BSC)		
L		0.500	0.600	0.700	L		0.020	0.024	0.028
L1		1.05 (BSC)			L1		0.041 (BSC)		
θ		0°	4°	8°	θ		0°	4°	8°



· TSSOP-16

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Inches	
	Min(mm)	Max(mm)		Min(in)	Max(in)
A		1.200	A		0.047
A1	0.050	0.150	A1	0.002	0.006
A2	0.800	1.050	A2	0.031	0.041
b	0.190	0.300	b	0.007	0.012
c	0.090	0.200	c	0.004	0.0089
D	4.900	5.100	D	0.193	0.201
E	6.200	6.600	E	0.244	0.260
E1	4.300	4.480	E1	0.169	0.176
e	0.65 (BSC)		e	0.0256 (BSC)	
K	0°	8°	K	0°	8°
L	0.450	0.750	L	0.018	0.030



Statement:

- XBLW reserves the right to modify the product manual without prior notice! Before placing an order, customers need to confirm whether the obtained information is the latest version and verify the completeness of the relevant information.
- Any semi-guide product is subject to failure or malfunction under specified conditions. It is the buyer's responsibility to comply with safety standards when using XBLW products for system design and whole machine manufacturing. And take the appropriate safety measures to avoid the potential in the risk of loss of personal injury or loss of property situation!
- XBLW products have not been licensed for life support, military, and aerospace applications, and therefore XBLW is not responsible for any consequences arising from the use of this product in these areas.
- If any or all XBLW products (including technical data, services) described or contained in this document are subject to any applicable local export control laws and regulations, they may not be exported without an export license from the relevant authorities in accordance with such laws.
- The specifications of any and all XBLW products described or contained in this document specify the performance, characteristics, and functionality of said products in their standalone state, but do not guarantee the performance, characteristics, and functionality of said products installed in Customer's products or equipment. In order to verify symptoms and conditions that cannot be evaluated in a standalone device, the Customer should ultimately evaluate and test the device installed in the Customer's product device.
- XBLW documentation is only allowed to be copied without any alteration of the content and with the relevant authorization. XBLW assumes no responsibility or liability for altered documents.
- XBLW is committed to becoming the preferred semiconductor brand for customers, and XBLW will strive to provide customers with better performance and better quality products.